

PerFET™ Power Transistor

FEATURES

- Excellent FOM
- AEC-Q101 Qualified
- Wettable Flank leads for Enhanced AOI
- 100% UIS and Rg tested
- 175°C Operating Junction Temperature
- RoHS Compliant
- Halogen-Free

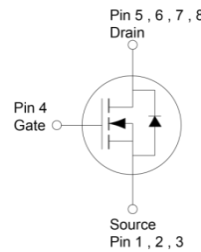
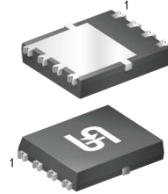
APPLICATIONS

- Automotive Applications
- Solenoid and Motor Drivers
- DC-DC Converters

PRODUCT SUMMARY			
PARAMETER	VALUE	UNIT	
V_{DS}	40	V	
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	2.5	mΩ
	$V_{GS} = 7V$	3	
Q_g	$V_{GS} = 10V$	59	nC



PDFN56U



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V_{DS}	40	V	
Gate-Source Voltage	V_{GS}	± 20	V	
Continuous Drain Current, Silicon limited	$T_C = 25^\circ\text{C}$	I_D	174	A
Continuous Drain Current (Note 1)	$T_C = 25^\circ\text{C}$	I_D	100	A
	$T_C = 100^\circ\text{C}$		100	
	$T_A = 25^\circ\text{C}$		26	
Pulsed Drain Current (Note 2)	I_{DM}	400	A	
Single Pulse Avalanche Current (Note 3)	I_{AS}	34.9	A	
Single Pulse Avalanche Energy (Note 3)	E_{AS}	182.3	mJ	
Total Power Dissipation	P_D	$T_C = 25^\circ\text{C}$	136	W
		$T_C = 125^\circ\text{C}$	45	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +175	$^\circ\text{C}$	

THERMAL RESISTANCE			
PARAMETER	SYMBOL	MAXIMUM	UNIT
Thermal Resistance – Junction to Case	$R_{\theta JC}$	1.1	$^\circ\text{C/W}$
Thermal Resistance – Junction to Ambient (Note 4)	$R_{\theta JA}$	50	$^\circ\text{C/W}$

NOTE:

1. Package current limit.
2. Pulse Width $\leq 100\mu\text{s}$.
3. $L = 0.3\text{mH}$, $V_{GS} = 10\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$.
4. Device on a PCB FR4 with 1 in² (single layer, 2 oz thick) copper area for drain connection.

ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 1mA	BV _{DSS}	40	--	--	V
Gate Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	V _{GS(TH)}	2.4	3	3.6	V
Gate-Source Leakage Current	V _{GS} = ±20V, V _{DS} = 0V	I _{GSS}	--	--	±100	nA
Drain-Source Leakage Current	V _{GS} = 0V, V _{DS} = 40V	I _{DSS}	--	--	1	μA
	V _{GS} = 0V, V _{DS} = 40V T _J = 125°C		--	--	100	
Drain-Source On-State Resistance (Note 5)	V _{GS} = 10V, I _D = 50A	R _{DS(on)}	--	1.8	2.5	mΩ
	V _{GS} = 7V, I _D = 50A		--	2	3	
Forward Transconductance (Note 5)	V _{DS} = 10V, I _D = 12.5A	g _{fs}	--	82	--	S
Dynamic (Note 6)						
Total Gate Charge	V _{GS} = 7V, V _{DS} = 25V, I _D = 26A	Q _g	--	42	63	nC
Total Gate Charge	V _{GS} = 10V, V _{DS} = 25V, I _D = 26A	Q _g	--	59	89	
Gate-Source Charge		Q _{gs}	--	19	38	
Gate-Drain Charge		Q _{gd}	--	11	22	
Input Capacitance	V _{GS} = 0V, V _{DS} = 25V, f = 1.0MHz	C _{iss}	--	3794	5691	pF
Output Capacitance		C _{oss}	--	785	1570	
Reverse Transfer Capacitance		C _{rss}	--	31	62	
Gate Resistance	f = 1.0MHz	R _g	--	0.8	--	Ω
Switching (Note 7)						
Turn-On Delay Time	V _{GS} = 10V, V _{DS} = 25V, I _D = 26A, R _G = 0.8Ω	t _{d(on)}	--	15.1	--	ns
Rise Time		t _r	--	70.6	--	
Turn-Off Delay Time		t _{d(off)}	--	27	--	
Fall Time		t _f	--	5.8	--	
Source-Drain Diode						
Diode Forward Voltage (Note 5)	V _{GS} = 0V, I _S = 50A	V _{SD}	--	--	1.1	V
Reverse Recovery Time	I _S = 26A,	t _{rr}	--	45.3	--	ns
Reverse Recovery Charge	di/dt = 100A/μs	Q _{rr}	--	55.7	--	nC

Notes:

5. Pulse test: Pulse Width ≤ 300μs, duty cycle ≤ 2%.
6. Defined by design. Not subject to production test.
7. Switching time is essentially independent of operating temperature.

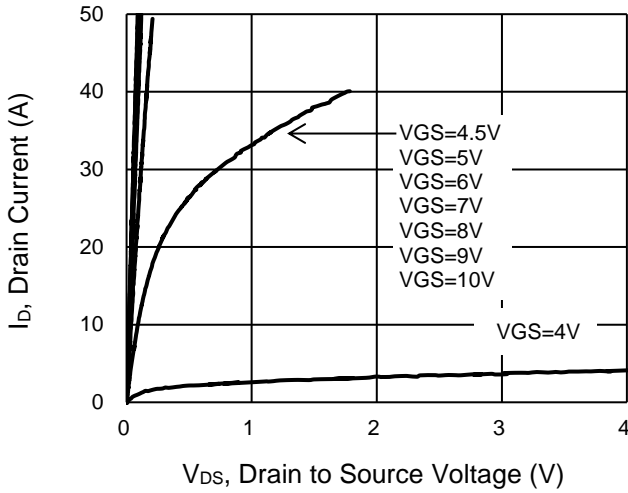
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TQM025NH04CR RLG	PDFN56U	2,500pcs / 13" Reel

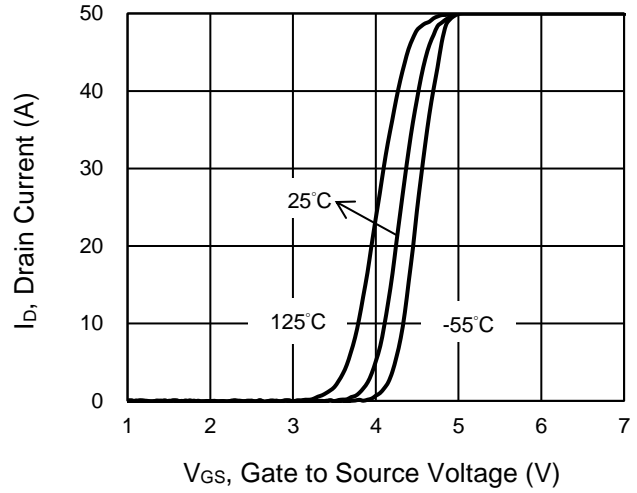
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

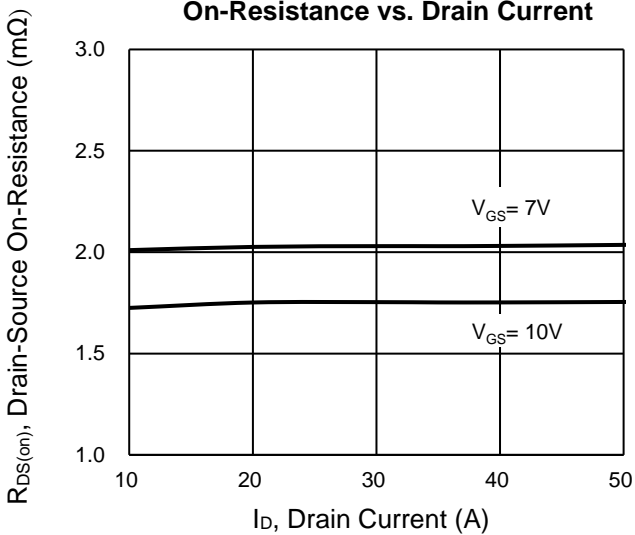
Output Characteristics



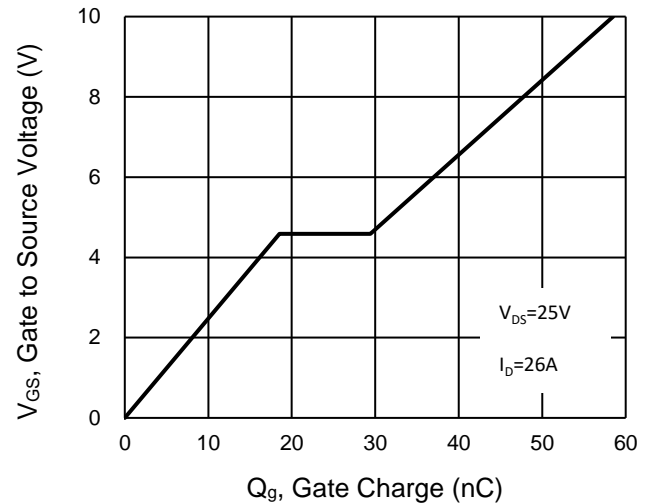
Transfer Characteristics



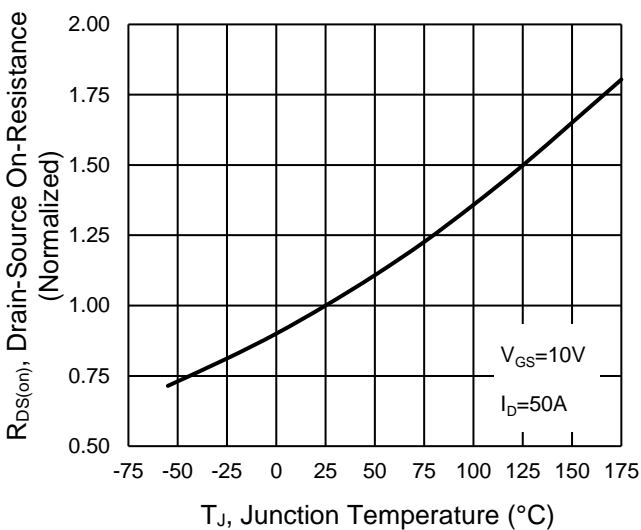
On-Resistance vs. Drain Current



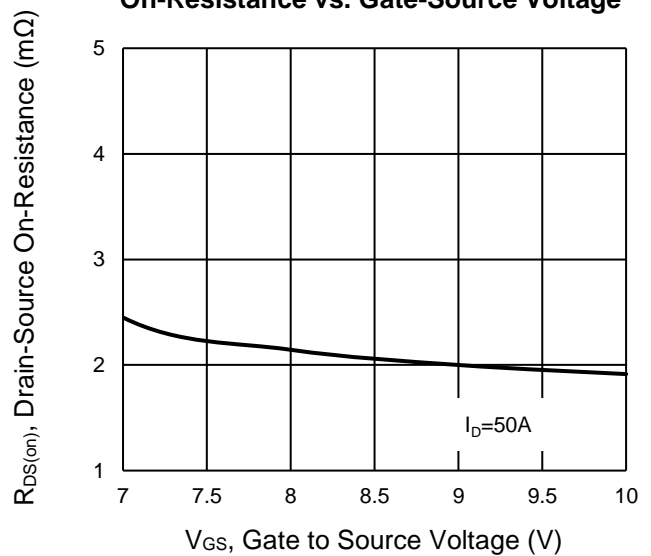
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

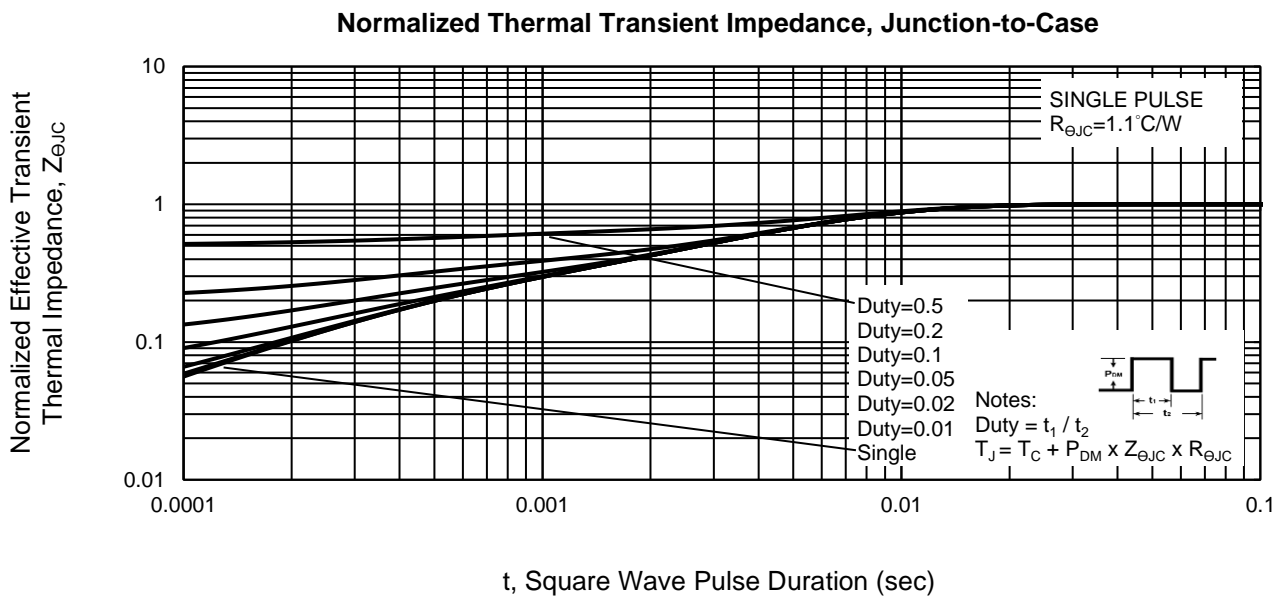
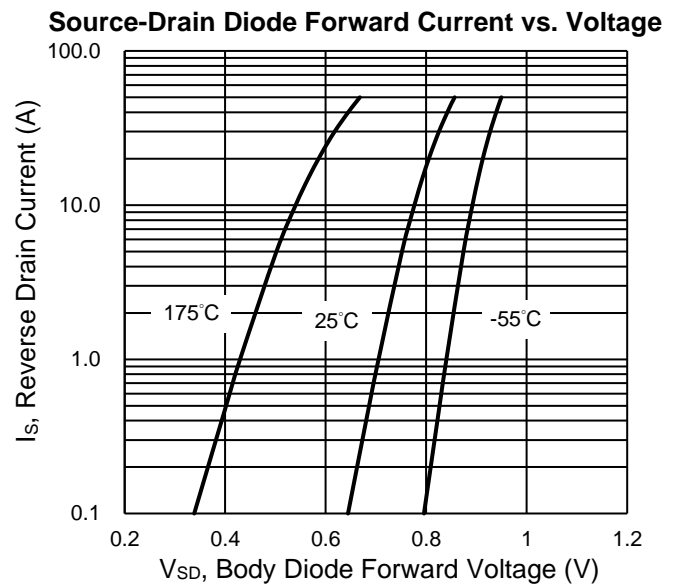
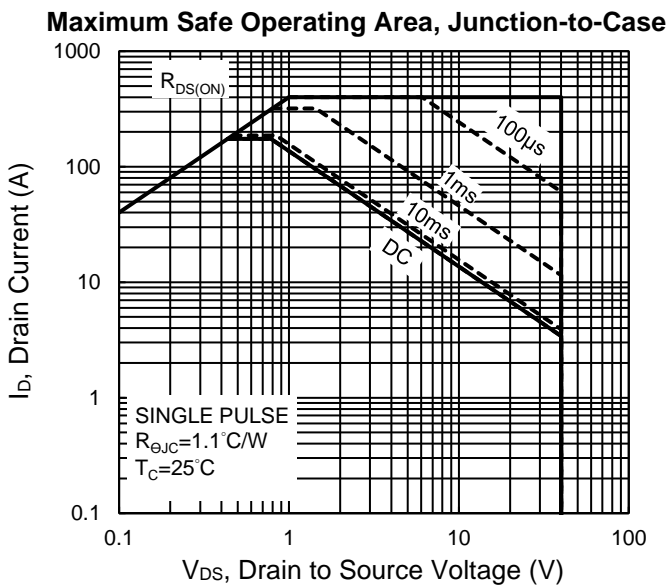
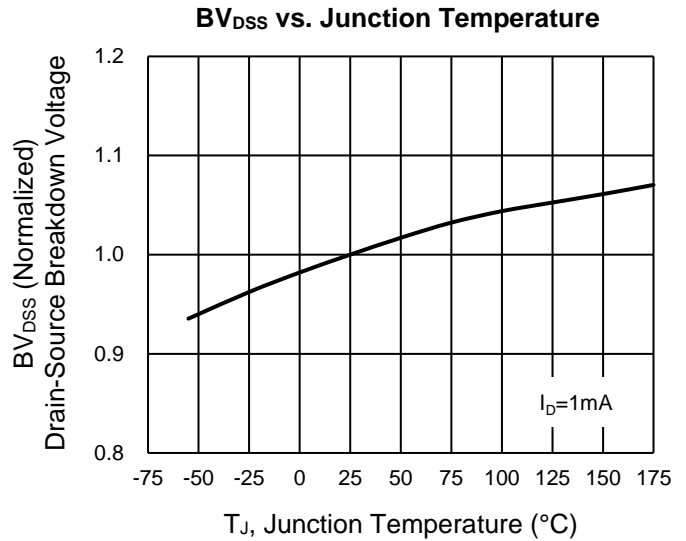
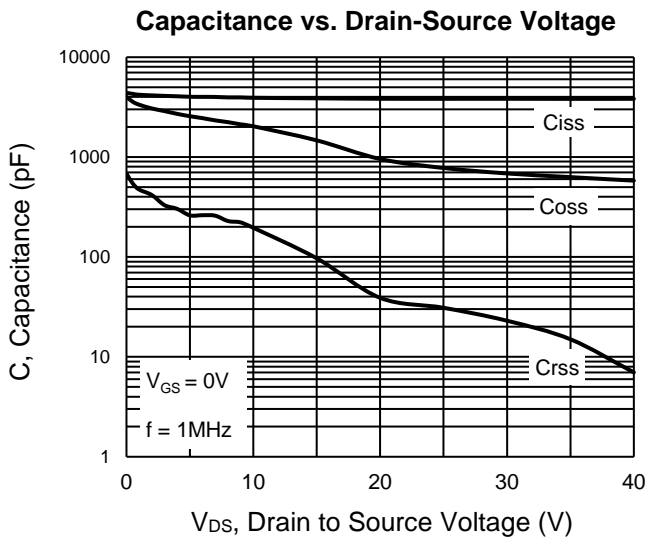


On-Resistance vs. Gate-Source Voltage



CHARACTERISTICS CURVES

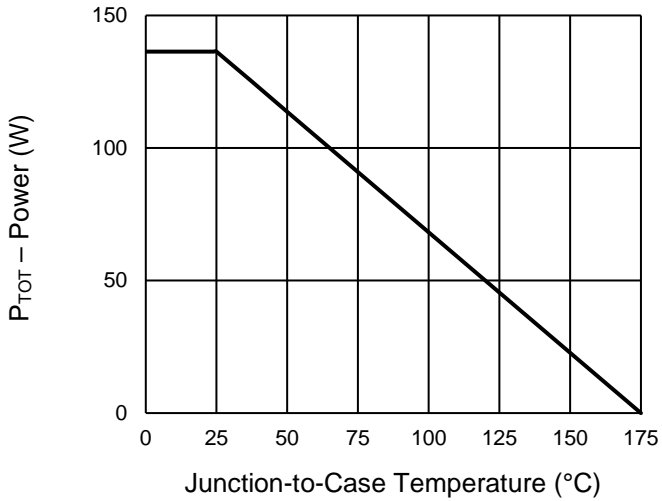
($T_A = 25^\circ\text{C}$ unless otherwise noted)



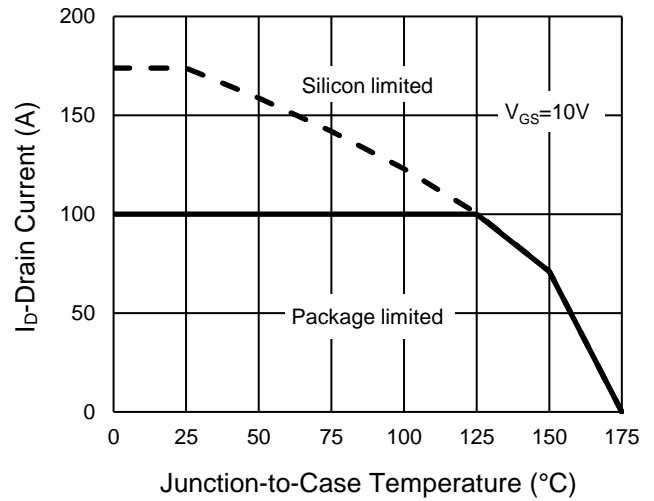
CHARACTERISTICS CURVES

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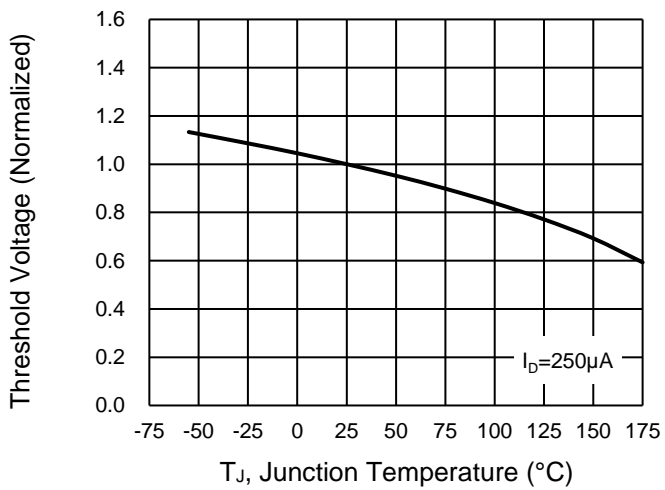
Power Dissipation



Drain Current

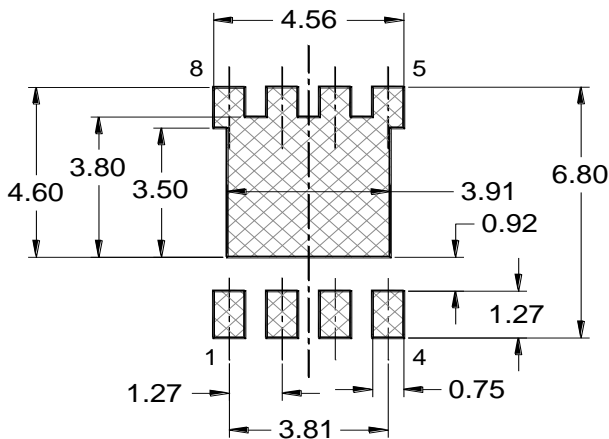
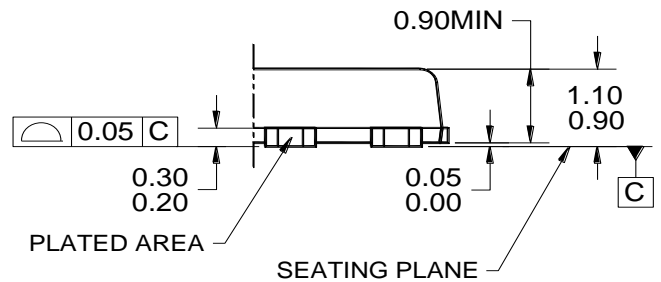
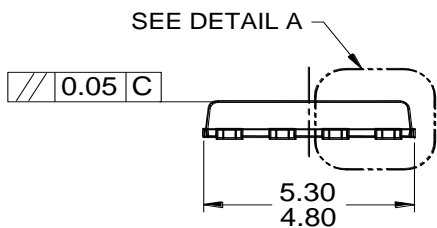
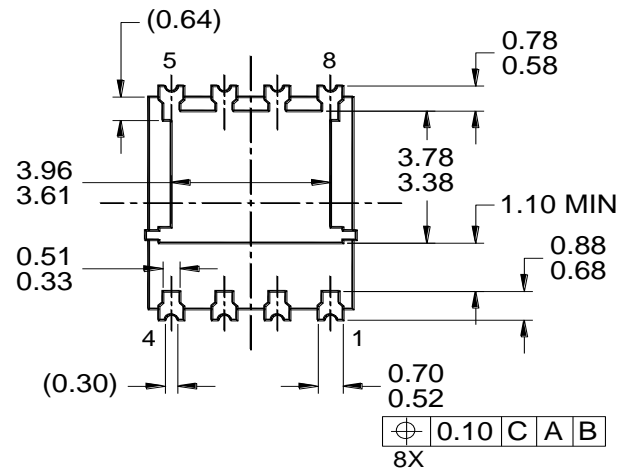
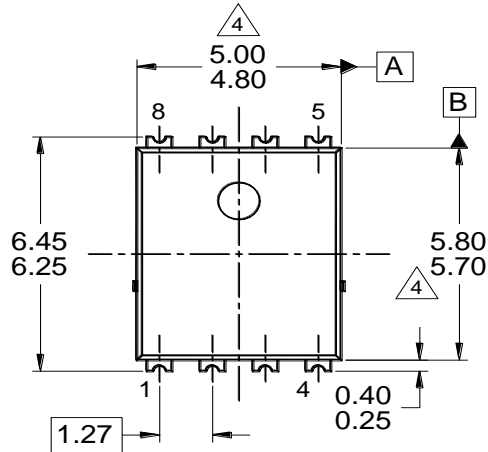


Normalized gate threshold voltage vs Temperature



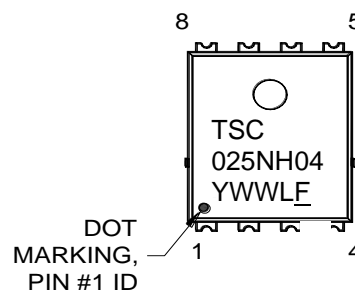
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56U



SUGGESTED PAD LAYOUT
(REFERENCE ONLY)

DETAIL A
(SCALE 2:1)



MARKING DIAGRAM

NOTES: UNLESS OTHERWISE SPECIFIED

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PACKAGE OUTLINE REFERENCE: JEITA ED-7500B, EIAJ SC-111BB.
4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DWG NO. REF: HQ2SD07-PDFN56U-023 REV B.

- Y = YEAR CODE
 WW = WEEK CODE (01~52)
 L = LOT CODE (1~9, A~Z)
 F = FACTORY CODE
 - = AEC-Q101 QUALIFIED

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